## NSN 5961-01-241-1192

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-241-1192 **Inclosure Material:** Metal **Overall Length:** Between 0.300 inches and 0.435 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.150 inches and 0.185 inches **Mounting Method:** Terminal **Terminal Circle Diameter:** Between 0.027 inches and 0.034 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.5 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 5.00 microamperes collector current, dc peak **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector major **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/434 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli